



256K X 8 OTP CMOS EPROM

Document Title 256K X 8 OTP CMOS EPROM

Revision History

Rev. No.	<u>History</u>	Issue Date	Remark
0.0	Initial issue	September 29, 2000	Preliminary
0.1	Change Program Verify VCC to 6.25V	March 14, 2001	
1.0	Final version release	October 7, 2003	Final



256K X 8 OTP CMOS EPROM

Features

262,144 X 8 bit organizationProgramming voltage: 12.75V

Access time: 55/70 ns (max.)
 Current: Operating: 30mA (max.) at 5MHz

Standby: 100µA (max.)

■ All inputs and outputs are directly TTL-compatible

■ Available in 32-pin DIP and 32-pin PLCC packages

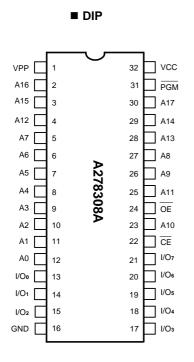
General Description

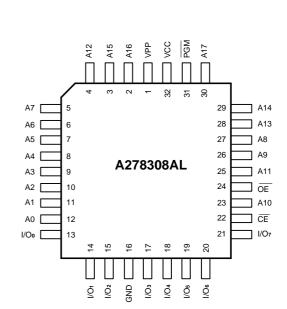
The A278308A chip is a high-performance 2,097,152 bit one-time programmable read only memory (OTP EPROM) organized as 256K by 8 bits. The A278308A requires only 5V power supply in normal read mode operation and any

input signals are TTL levels. The A278308A is available in industry standard 32 pin dual-in-line and 32 pin PLCC packages.

■ PLCC

Pin Configurations





1



Pin Configurations

Pin Name	Function
A0-A17	Address Inputs
I/O7-I/O0	Data Inputs / Outputs
CE	Chip Enable
ŌĒ	Output Enable
PGM	Program Strobe
VPP	Program Power Supply
VCC	Power Supply
GND	Ground

Operating Modes and Truth Table

Mode	CE	ŌĒ	PGM	A0	A 1	A 9	VPP	vcc	I/O7-I/O ₀
Read	VIL	VIL	Х	Х	Х	Х	VCC	VCC	Data Out
Output Disable	VIL	Vih	Х	Х	Х	Х	VCC	VCC	Hi-Z
Standby	Vih	Х	Х	Х	Х	Х	VCC	VCC	Hi-Z
Program	VIL	Vih	Vı⊾ Pulse	Х	Х	Х	12.75V	6.25V	Data In
Program Verify	VIL	VIL	Vін	Х	Х	Х	12.75V	6.25V	Data Out
Program Inhibit	Vih	Х	Х	Х	Х	Х	12.75V	6.25V	Hi-Z
Manufacturer Code ⁽³⁾	VIL	VIL	Vih	VIL	VIL	VID	VCC	VCC	37H
Device Code ⁽³⁾	VIL	VIL	Vih	Vih	VIL	Vid	VCC	VCC	64H
Continuation Code ⁽³⁾	VIL	VIL	Vih	VIL	Vih	Vid	VCC	VCC	7FH

Notes:

- 1. X = Either Vih or Vil.
- 2. $V_{ID} = 12V \pm 0.5V$.
- 3. A2 \sim A8 = A10 \sim A17 = V_{IL} (For auto identification)



Functional Description

Read Mode

The A278308A has two control functions, both of which must be logically active in order to obtain data at the outputs. \overline{CE} is the power control and should be used for device selection. \overline{OE} is the output control and should be used to data to the output pins, which is independent of device selection. Assuming that addresses are stable, address access time (taa) is equal to the delay from \overline{CE} to output (tce). Data is available at the output after a delay (toe) from the falling edge of \overline{OE} , as long as \overline{CE} has been low and the addresses have been stable for at least tacc - toe.

Standby Mode

The A278308A has a standby mode which reduces the active current from 30mA to $100\mu A.$ The A278308A is placed in the standby mode by applying a CMOS high signal to $\overline{\text{CE}}$. When in the standby mode, the output are in a high impedance state, independent of the $\overline{\text{OE}}$.

Absolute Maximum Ratings*

Auto Identify Mode

The auto identify mode allows the reading out of a binary code from a EPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment for the purpose of automatically matching the device to be programmed with its corresponding programming algorithm.

To activate the mode, the programming equipment must apply 12.0V \pm 0.5V on address line A9 of the A278308A. Three identification code can be read from data output pin by toggling A0 and A1. The other addresses must be held at VIL during this mode. Byte 0 (with A0 at VIL, A1 at VIL) represents the manufacturer code which is 37H. Byte 1 and Byte 2 represent the device code and continuation code, which is 64H and 7FH respectively. All identifiers for these codes will possess odd parity, with MSB (IO7) defined the parity bit.

*Comments

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

Notes

- 1. During voltage transitions, the input may undershoot GND to -2.0V for periods less than 20 ns. Maximum DC voltage on input and I/O may overshoot to VCC + 2.0V for periods less than 20 ns.
- 2. When transitions, A9 and VPP may undershoot GND to -2.0V for periods less than 20 ns. Maximum DC input voltage on A9 and VPP is +13.5V which may overshoot to 14.0V for period less than 20 ns.



Read Mode DC Electrical Characteristics (Ta = 0° C to 70° C, VCC = 5V \pm 10%, VPP = VCC)

Symbol	Parameter	Min.	Max.	Unit	Conditions
Voн	Output High Voltage	2.4		V	Іон = -400μΑ
Vol	Output Low Voltage		0.4	V	loL = 2.1mA
Vih	Input High Voltage	2.0	VCC + 0.5	V	
VIL	Input Low Voltage	-0.5	0.8	V	
lu	Input Leakage Current	-1	+1	μА	VCC = max. Vin = 0V to VCC
lLO	Output Leakage Current	-1	+1	μА	VCC = max. Vout = 0V to VCC
lcc	VCC Read Operating Current		30	mA	VCC = max. \overline{CE} = V _I L, \overline{OE} = V _I L lout = 0mA, at 5MHz
lsв	VCC Standby Current (TTL)		1	mA	VCC = max. $\overline{\text{CE}}$ = Vін
ls _{B1}	VCC Standby Current (CMOS)		100	μΑ	$\frac{\text{VCC} = \text{max.}}{\text{CE}} = \text{VCC} - 0.2\text{V}$
lpp	VPP Current During Read		10	μΑ	$\overline{CE} = \overline{OE} = VIL,$ VPP = VCC
lıb	A9 Auto Select Current		100	μΑ	A9 = VID, VCC = max.

Capacitance (Ta = 25° C, f = 1.0MHz)

Symbol	Parameter	Min.	Max.	Unit	Conditions
Cin	Input Capacitance		8	pF	Vin = 0V
Cout	Output Capacitance		8	pF	Vout = 0V

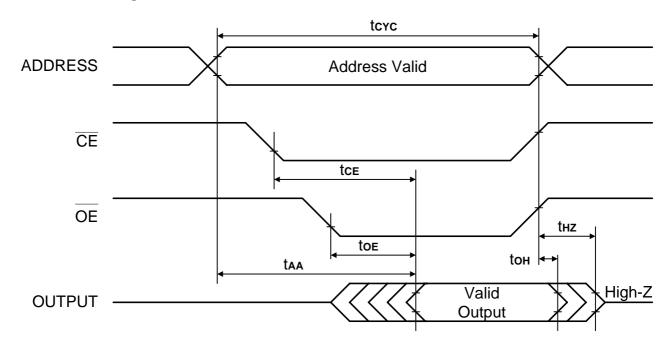
^{*} These parameters are sampled and not 100% tested.



Read Mode AC Characteristics (Ta = 0° C to 70° C, VCC = 5V \pm 10%, VPP = VCC)

Symbol	abol Parameter		ns	70	Unit	
		Min.	Max.	Min.	Max.	
tcyc	Cycle Time	55		70		ns
taa	Address Access Time		55		70	ns
tce	Chip Enable Access Time		55		70	ns
toe	Output Enable Access Time		30		35	ns
toн	Output Hold after Address, $\overline{\sf CE}$ or $\overline{\sf OE}$, whichever Occurred First	0		0		ns
tнz	Output High Z Delay		20		20	ns

Read Mode Switching Waveforms



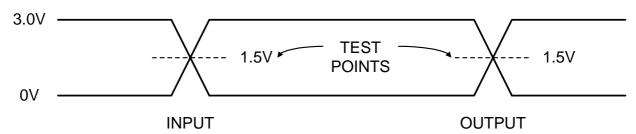


AC Measurement Conditions

for 55 ns ① Input Rise and Fall Times ≤ 10 ns

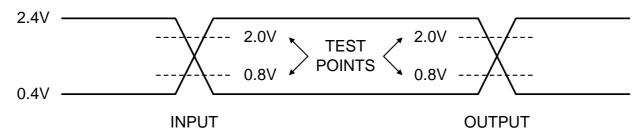
② Input Pulse Voltage: 0V to 3Volt

3 Input and Output Timing Ref. Voltage: 1.5Volt

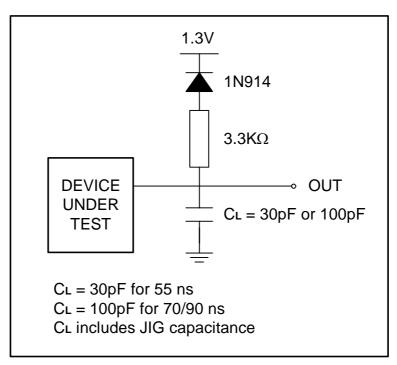


for 70 ns ① Input Rise and Fall Times \leq 10 ns

- ② Input Pulse Voltage: 0.4V to 2.4Volt
- 3 Input and Output Timing Ref. Voltage: 0.8V to 2.0Volt



AC Testing Load Circuit





Programming and Program Verify

The programming flowchart is shown in Page 10.

The A278308A is shipped with all bits being set to "1". Programming causes relevant bits to be changed to "0". The programming mode is started by setting VCC to +6.25V and VPP to +12.75V, while $\overline{\text{CE}}$ and $\overline{\text{PGM}}$ are at V_{IL}, and $\overline{\text{OE}}$ is at V_{IH}. Data to be programmed can be directly input in the 8 bit format through the data bus.

The write programming algorithm reduces programming time by using $100\mu s$ pulse followed by a byte verification to determine whether the byte has been successfully programmed. If the data does not pass the verification, an

additional pulse programming is applied for a maximum of 25 pulses. On completion of 1 byte programming and, The verified address is incremented. After the final address is completed, all bytes are verified again with VCC = 5.0 Volt.

Program Inhibit

This mode is used to program one of multiple A278308A whose $\overline{\text{OE}}$, $\overline{\text{PGM}}$, VPP, VCC, address bus and data bus are connected in parallel. When programming is performed, other A278308A can be inhibited from being programmed by setting their $\overline{\text{CE}}$ pins to Vih.

Programming Mode DC Characteristics (Ta = 0° C to 70° C, VCC = 6.25V ± 0.25 V, VPP = 12.75V ± 0.25 V)

Symbol	Parameter	Min.	Max.	Unit	Test Conditions
Vон	Output High Voltage	2.4		V	Іон = -400μΑ
Vol	Output Low Voltage		0.4	V	loL = 2.1mA
Vih	Input High Voltage	2.0	VCC + 0.5	V	
VIL	Input Low Voltage	-0.5	0.8	V	
lu	Input Leakage Current	-1	+1	μΑ	VCC = max. Vin = 0V to VCC
lcc	VCC Current During Program		50	mA	
Ірр	VPP Current During Program		50	mA	CE = VIL
Vid	A9 Auto Select Voltage	11.5	12.5	V	A9 = VID
VCC1	Programming Supply Voltage	6.0	6.5	V	
VPP1	Programming Voltage	12.5	13	V	

Note: VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP.

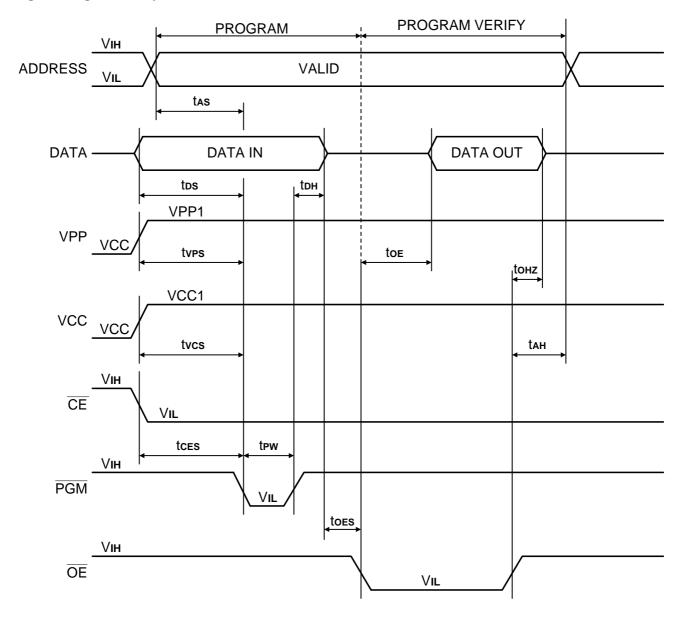


Programming Mode AC Characteristics (Ta = 0° C to 70° C, VCC= 6.25V \pm 0.25V, VPP = 12.75V \pm 0.25V)

Symbol	Parameter	Min.	Max.	Unit
tas	Address Valid to Program Low	2		μs
tos	Input Valid to Program Low	2		μs
tvps	VPP High to Program Low	2		μs
tvcs	VCC High to Program Low	2		μs
tces	CE Low to Program Low	2		μS
tpw	Program Pulse Width	95	105	μs
tон	Program High to Input transition	2		μs
toes	Input Transition to OE Low	2		μS
toe	OE Low to Output Valid		100	ns
toнz	OE High to Output Hi-Z		130	ns
tah	OE High to Address Transition	0		ns

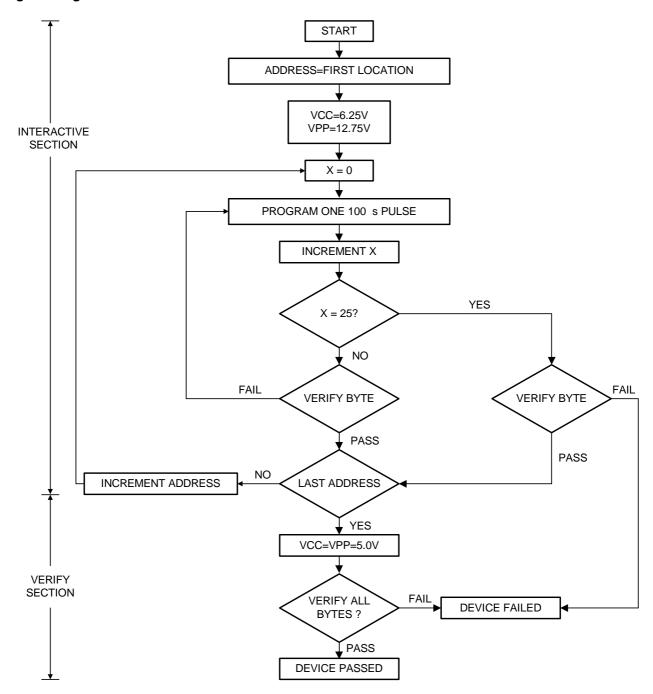


Programming and Verify Mode AC Waveforms





Programming Flowchart





Ordering Information

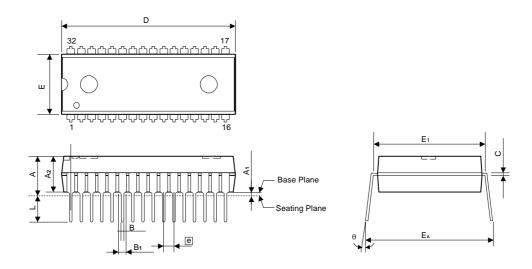
Part No.	Access Time (ns)	Operating Current Max. (mA) at 5MHz	Standby Current Max. (μΑ)	Package
A278308A-55	55	30	100	32Pin DIP
A278308AL-55	55	30	100	32Pin PLCC
A278308A-70	70	30	100	32Pin DIP
A278308AL-70	70	30	100	32Pin PLCC



Package Information

P-DIP 32L Outline Dimensions

unit: inches/mm



Symbol	Dimen	sions in	inches	Dimensions in mm			
Cymbol	Min	Nom	Max	Min	Nom	Max	
Α	-	-	0.210	-	-	5.334	
A1	0.015	-	-	0.381	-	-	
A2	0.149	0.154	0.159	3.785	3.912	4.039	
В	-	0.018	-	-	0.457	-	
B1	-	0.050	-	-	1.270	-	
С	-	0.010	-	-	0.254	-	
D	1.645	1.650	1.655	41.783	41.91	42.037	
Е	0.537	0.542	0.547	13.64	13.767	13.894	
E1	0.590	0.600	0.610	14.986	15.240	15.494	
EA	0.630	0.650	0.670	16.002	16.510	17.018	
е	-	0.100	-	-	2.540	-	
L	0.120	0.130	0.140	3.048	3.302	3.556	
θ	0°	-	15°	0°	-	15°	

Notes:

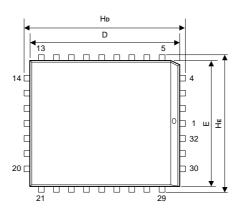
- 1. The maximum value of dimension D includes end flash.
- 2. Dimension E does not include resin fins.

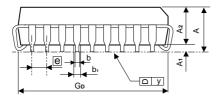


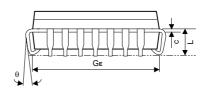
Package Information

PLCC 32L Outline Dimension

unit: inches/mm







Symbol	Dimensions in inches			Dimensions in mm			
Syllibol	Min	Nom	Max	Min	Nom	Max	
А	-	-	0.134	-	-	3.40	
A1	0.0185	-	i	0.47	ı	-	
A2	0.105	0.110	0.115	2.67	2.80	2.93	
b ₁	0.026	0.028	0.032	0.66	0.71	0.81	
b	0.016	0.018	0.021	0.41	0.46	0.54	
С	0.008	0.010	0.014	0.20	0.254	0.35	
D	0.547	0.550	0.553	13.89	13.97	14.05	
Е	0.447	0.450	0.453	11.35	11.43	11.51	
е	0.044	0.050	0.056	1.12	1.27	1.42	
GD	0.490	0.510	0.530	12.45	12.95	13.46	
GE	0.390	0.410	0.430	9.91	10.41	10.92	
Hp	0.585	0.590	0.595	14.86	14.99	15.11	
HE	0.485	0.490	0.495	12.32	12.45	12.57	
L	0.075	0.090	0.095	1.91	2.29	2.41	
у	-	-	0.003	-		0.075	
θ	0°	-	10°	0°	-	10°	

Notes:

- 1. Dimensions D and E do not include resin fins.
- 2. Dimensions G_D & G_E are for PC Board surface mount pad pitch design reference only.